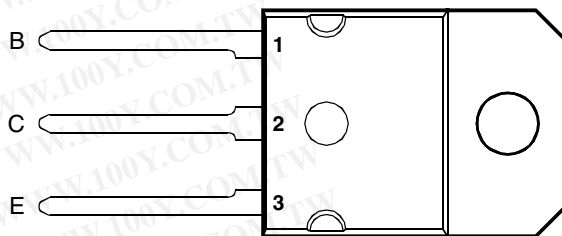


- Rugged Triple-Diffused Planar Construction
- 10 A Continuous Collector Current
- Operating Characteristics Fully Guaranteed at 100°C
- 1000 Volt Blocking Capability
- 125 W at 25°C Case Temperature

**SOT-93 PACKAGE  
(TOP VIEW)**



Pin 2 is in electrical contact with the mounting base.

MDTRAAA

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**absolute maximum ratings at 25°C case temperature (unless otherwise noted)**

| RATING                                                            |          | SYMBOL    | VALUE       | UNIT |
|-------------------------------------------------------------------|----------|-----------|-------------|------|
| Collector-base voltage ( $I_E = 0$ )                              | TIPL765  | $V_{CB0}$ | 850         | V    |
|                                                                   | TIPL765A |           | 1000        |      |
| Collector-emitter voltage ( $V_{BE} = 0$ )                        | TIPL765  | $V_{CES}$ | 850         | V    |
|                                                                   | TIPL765A |           | 1000        |      |
| Collector-emitter voltage ( $I_B = 0$ )                           | TIPL765  | $V_{CEO}$ | 400         | V    |
|                                                                   | TIPL765A |           | 450         |      |
| Emitter-base voltage                                              |          | $V_{EBO}$ | 10          | V    |
| Continuous collector current                                      |          | $I_C$     | 10          | A    |
| Peak collector current (see Note 1)                               |          | $I_{CM}$  | 15          | A    |
| Continuous device dissipation at (or below) 25°C case temperature |          | $P_{tot}$ | 125         | W    |
| Operating junction temperature range                              |          | $T_j$     | -65 to +150 | °C   |
| Storage temperature range                                         |          | $T_{stg}$ | -65 to +150 | °C   |

NOTE 1: This value applies for  $t_p \leq 10$  ms, duty cycle  $\leq 2\%$ .

**PRODUCT INFORMATION**

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**electrical characteristics at 25°C case temperature (unless otherwise noted)**

| PARAMETER                                          | TEST CONDITIONS                                                                                                                                                                                                            | MIN        | TYP | MAX                      | UNIT          |
|----------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------|-----|--------------------------|---------------|
| $V_{CE(sus)}$ Collector-emitter sustaining voltage | $I_C = 100 \text{ mA}$ $L = 25 \text{ mH}$ (see Note 2)<br>TIPL765<br>TIPL765A                                                                                                                                             | 400<br>450 |     |                          | V             |
| $I_{CES}$ Collector-emitter cut-off current        | $V_{CE} = 850 \text{ V}$ $V_{BE} = 0$<br>$V_{CE} = 1000 \text{ V}$ $V_{BE} = 0$<br>$V_{CE} = 850 \text{ V}$ $V_{BE} = 0$ $T_C = 100^\circ\text{C}$<br>$V_{CE} = 1000 \text{ V}$ $V_{BE} = 0$ $T_C = 100^\circ\text{C}$     |            |     | 50<br>50<br>200<br>200   | $\mu\text{A}$ |
| $I_{CEO}$ Collector cut-off current                | $V_{CE} = 400 \text{ V}$ $I_B = 0$<br>$V_{CE} = 450 \text{ V}$ $I_B = 0$                                                                                                                                                   |            |     | 50<br>50                 | $\mu\text{A}$ |
| $I_{EBO}$ Emitter cut-off current                  | $V_{EB} = 10 \text{ V}$ $I_C = 0$                                                                                                                                                                                          |            |     | 1                        | mA            |
| $h_{FE}$ Forward current transfer ratio            | $V_{CE} = 5 \text{ V}$ $I_C = 0.5 \text{ A}$ (see Notes 3 and 4)                                                                                                                                                           | 15         |     | 60                       |               |
| $V_{CE(sat)}$ Collector-emitter saturation voltage | $I_B = 0.4 \text{ A}$ $I_C = 2 \text{ A}$<br>$I_B = 1 \text{ A}$ $I_C = 5 \text{ A}$ (see Notes 3 and 4)<br>$I_B = 2 \text{ A}$ $I_C = 10 \text{ A}$<br>$I_B = 2 \text{ A}$ $I_C = 10 \text{ A}$ $T_C = 100^\circ\text{C}$ |            |     | 0.5<br>1.0<br>2.5<br>5.0 | V             |
| $V_{BE(sat)}$ Base-emitter saturation voltage      | $I_B = 0.4 \text{ A}$ $I_C = 2 \text{ A}$<br>$I_B = 1 \text{ A}$ $I_C = 5 \text{ A}$ (see Notes 3 and 4)<br>$I_B = 2 \text{ A}$ $I_C = 10 \text{ A}$<br>$I_B = 2 \text{ A}$ $I_C = 10 \text{ A}$ $T_C = 100^\circ\text{C}$ |            |     | 1.1<br>1.3<br>1.7<br>1.6 | V             |
| $f_t$ Current gain bandwidth product               | $V_{CE} = 10 \text{ V}$ $I_C = 0.5 \text{ A}$ $f = 1 \text{ MHz}$                                                                                                                                                          |            | 8   |                          | MHz           |
| $C_{ob}$ Output capacitance                        | $V_{CB} = 20 \text{ V}$ $I_E = 0$ $f = 0.1 \text{ MHz}$                                                                                                                                                                    |            | 150 |                          | pF            |

- NOTES: 2. Inductive loop switching measurement.  
3. These parameters must be measured using pulse techniques,  $t_p = 300 \mu\text{s}$ , duty cycle  $\leq 2\%$ .  
4. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

**thermal characteristics**

| PARAMETER                                           | MIN | TYP | MAX | UNIT               |
|-----------------------------------------------------|-----|-----|-----|--------------------|
| $R_{\theta JC}$ Junction to case thermal resistance |     |     | 1   | $^\circ\text{C/W}$ |

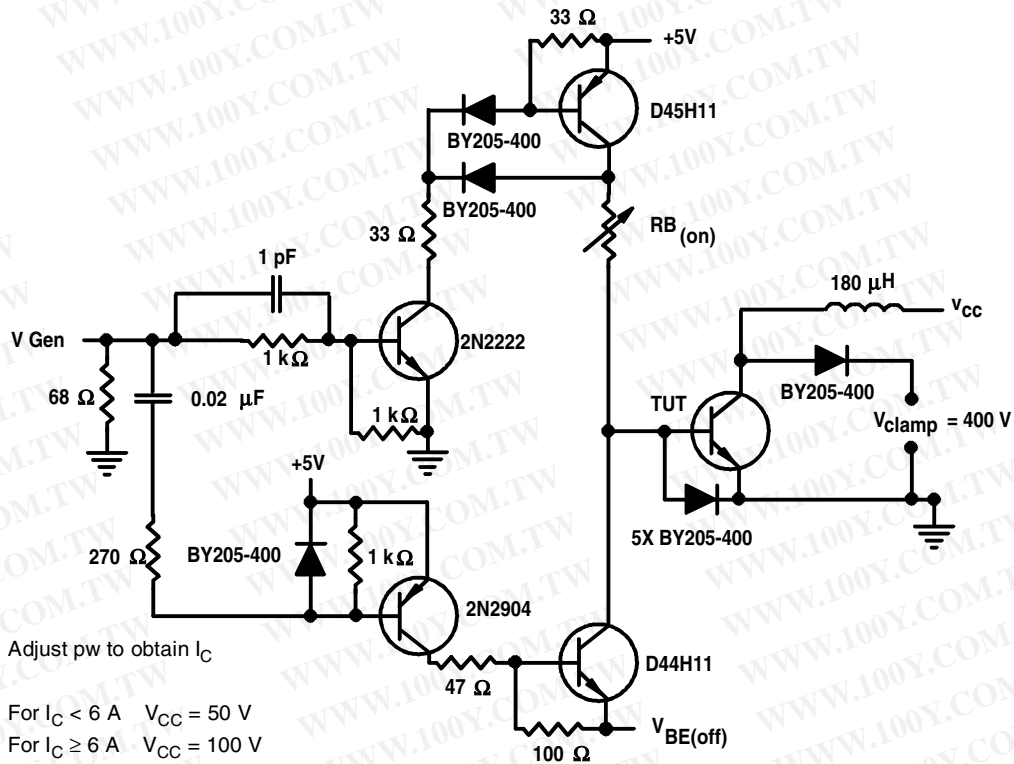
**inductive-load-switching characteristics at 25°C case temperature (unless otherwise noted)**

| PARAMETER                     | TEST CONDITIONS †                                                                                                              | MIN | TYP | MAX | UNIT          |
|-------------------------------|--------------------------------------------------------------------------------------------------------------------------------|-----|-----|-----|---------------|
| $t_{sv}$ Voltage storage time | $I_C = 10 \text{ A}$ $I_{B(on)} = 2 \text{ A}$ (see Figures 1 and 2)<br>$V_{BE(off)} = -5 \text{ V}$                           |     |     | 2   | $\mu\text{s}$ |
| $t_{rv}$ Voltage rise time    |                                                                                                                                |     |     | 300 | ns            |
| $t_{fi}$ Current fall time    |                                                                                                                                |     |     | 200 | ns            |
| $t_{ti}$ Current tail time    |                                                                                                                                |     |     | 50  | ns            |
| $t_{xo}$ Cross over time      |                                                                                                                                |     |     | 400 | ns            |
| $t_{sv}$ Voltage storage time | $I_C = 10 \text{ A}$ $I_{B(on)} = 2 \text{ A}$ (see Figures 1 and 2)<br>$V_{BE(off)} = -5 \text{ V}$ $T_C = 100^\circ\text{C}$ |     |     | 3.5 | $\mu\text{s}$ |
| $t_{rv}$ Voltage rise time    |                                                                                                                                |     |     | 400 | ns            |
| $t_{fi}$ Current fall time    |                                                                                                                                |     |     | 300 | ns            |
| $t_{ti}$ Current tail time    |                                                                                                                                |     |     | 80  | ns            |
| $t_{xo}$ Cross over time      |                                                                                                                                |     |     | 500 | ns            |

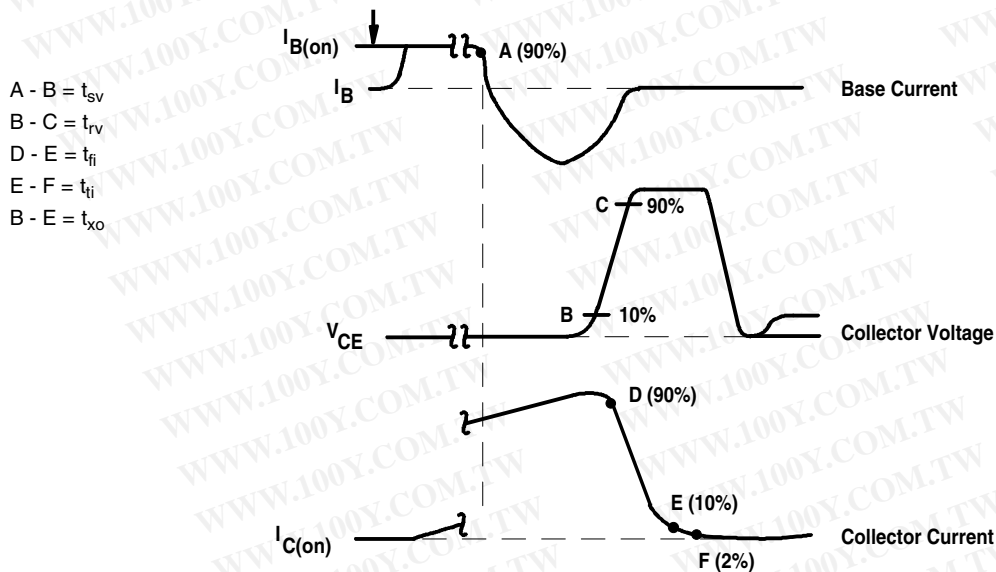
† Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

**PRODUCT INFORMATION**

**PARAMETER MEASUREMENT INFORMATION**



**Figure 1. Inductive-Load Switching Test Circuit**



NOTES: A. Waveforms are monitored on an oscilloscope with the following characteristics:  $t_r < 15\text{ ns}$ ,  $R_{in} > 10\ \Omega$ ,  $C_{in} < 11.5\text{ pF}$ .  
 B. Resistors must be noninductive types.

**Figure 2. Inductive-Load Switching Waveforms**

**PRODUCT INFORMATION**

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TYPICAL CHARACTERISTICS

TYPICAL DC CURRENT GAIN  
VS  
COLLECTOR CURRENT

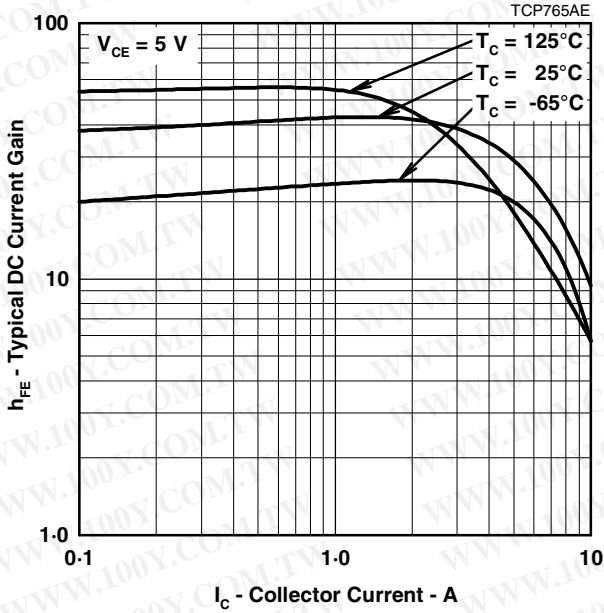


Figure 3.

COLLECTOR-EMITTER SATURATION VOLTAGE  
VS  
BASE CURRENT

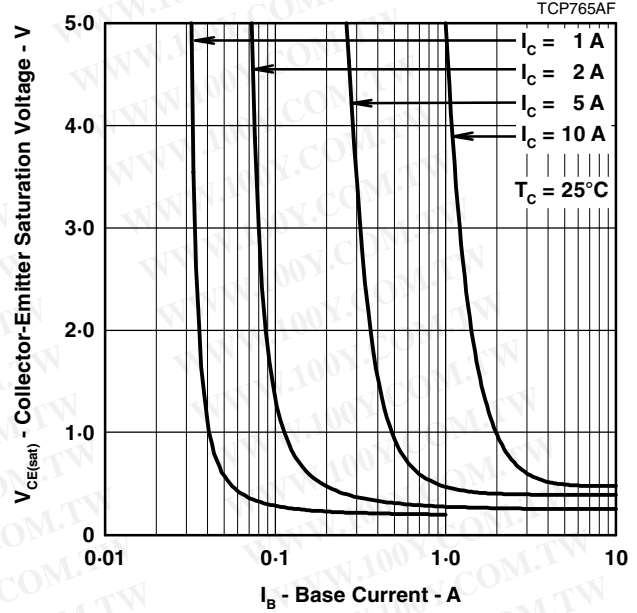


Figure 4.

COLLECTOR-EMITTER SATURATION VOLTAGE  
VS  
BASE CURRENT

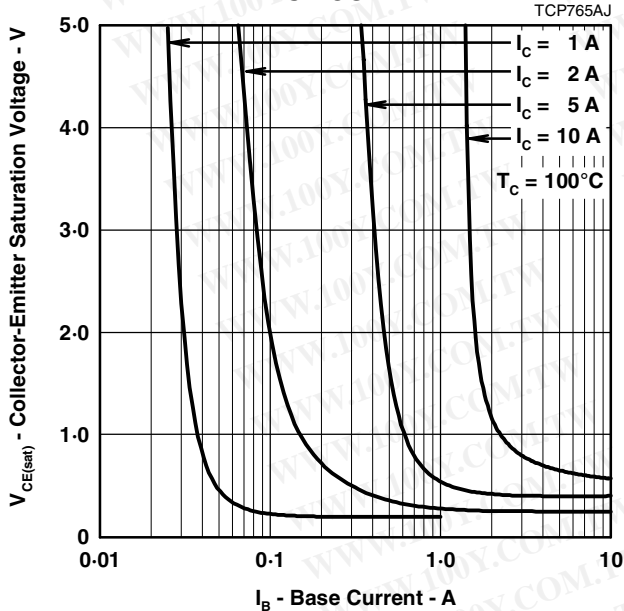


Figure 5.

BASE-EMITTER SATURATION VOLTAGE  
VS  
BASE CURRENT

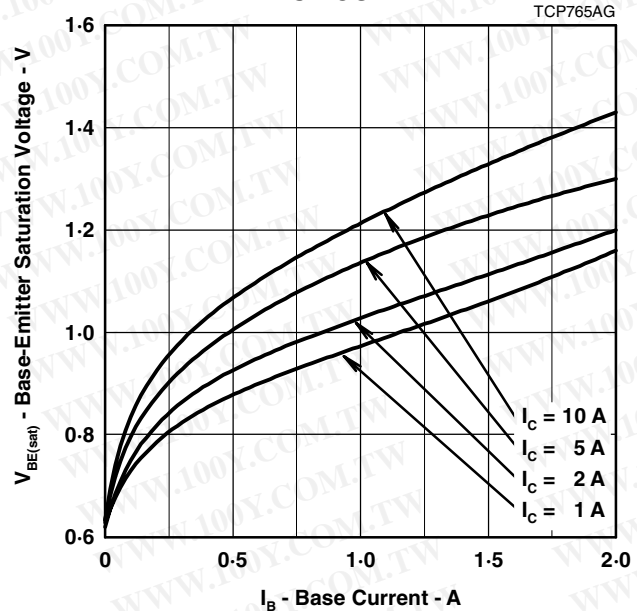


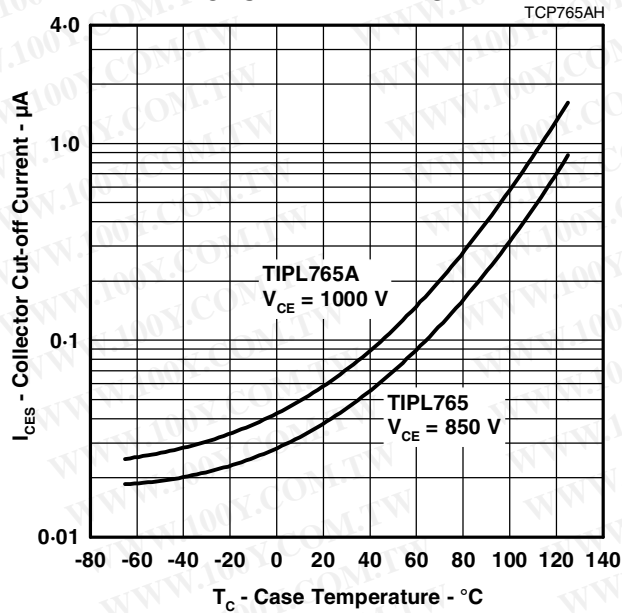
Figure 6.

**PRODUCT INFORMATION**

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**TYPICAL CHARACTERISTICS**

**COLLECTOR CUT-OFF CURRENT  
VS  
CASE TEMPERATURE**



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Figure 7.

**MAXIMUM SAFE OPERATING REGIONS**

**MAXIMUM FORWARD-BIAS  
SAFE OPERATING AREA**

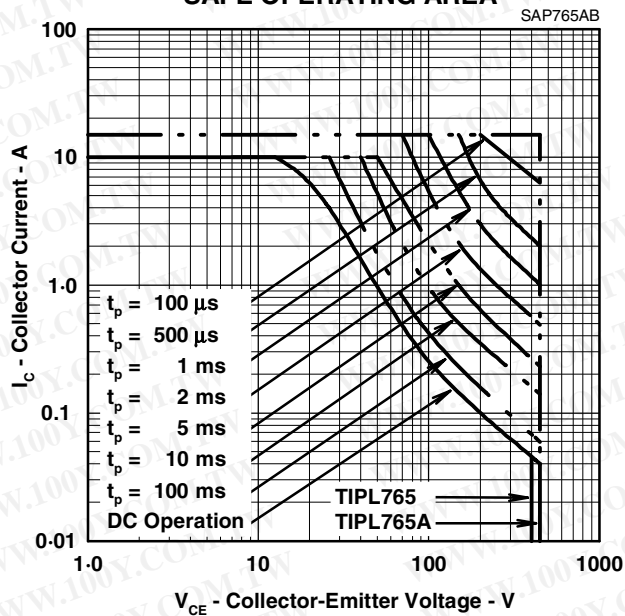


Figure 8.

**PRODUCT INFORMATION**

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